10/587845

#### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Risho KOH, et al.

Title:

FIELD EFFECT TRANSISTOR AND METHOD FOR PRODUCING

THE SAME

Appl. No.:

Unassigned

International

01/28/2005

Filing Date:

371(c) Date:

07/28/2006

Examiner:

Unassigned

Art Unit:

Unassigned

# INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR §1.56

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Submitted herewith on Form PTO/SB/08 is a listing of documents known to Applicants in order to comply with Applicants' duty of disclosure pursuant to 37 CFR §1.56.

A copy of each non-U.S. patent document and each non-patent document is being submitted to comply with the provisions of 37 CFR §1.97 and §1.98.

The submission of any document herewith, which is not a statutory bar, is not intended as an admission that such document constitutes prior art against the claims of the present application or that such document is considered material to patentability as defined in 37 CFR §1.56(b). Applicants do not waive any rights to take any action which would be appropriate to antedate or otherwise remove as a competent reference any document which is determined to be a *prima facie* art reference against the claims of the present application.

IAPS ROC'D FOTATO 28 JUL 2006

Atty. Dkt. No. 040373-0396

10/587845

#### TIMING OF THE DISCLOSURE

The listed documents are being submitted in compliance with 37 CFR §1.97(b), within three (3) months of the date of entry of the national stage as set forth in 37 CFR §1.491.

#### RELEVANCE OF EACH DOCUMENT

Document A1 is a U.S. counterpart of Document A4.

Document A2 relates to a double-gate FET device and manufacturing method of the same, capable of solving floating body effect and improving characteristics of the device and which provides a manufacturing method of the same.

Document A3 relates to a semiconductor device which can improve element characteristics.

Document A5 relates to a field effect transistor and its manufacturing method providing a sidewall of an insulation film on a gate electrode.

Document A6 relates to a field effect transistor and manufacturing method thereof to easily apply a vertical field effect transistor to an LSI by proving a structure in common and forming process of a source/drain region and a gate electrode.

The relevance of Document A8 is described in the present application.

Documents A4 and A7 listed on the attached PTO/SB/08 were cited as being relevant during the prosecution of the corresponding International application. A copy of the International Search Report is attached setting forth the portion of each document considered relevant by the examiner. An English translation of each of the foreign-language documents is not readily available. However, the absence of such translation does not relieve the PTO from its duty to consider the submitted foreign language document (37 CFR §1.98 and MPEP §609). English language abstracts are attached.

## IAPS Rec'd PCT/PTO 28 JUL 2006

Atty. Dkt. No. 040373-0396

10/587845

Applicants respectfully request that each listed document be considered by the Examiner and be made of record in the present application and that an initialed copy of Form PTO/SB/08 be returned in accordance with MPEP §609.

Although Applicant believes that no fee is required for this Request, the Commissioner is hereby authorized to charge any additional fees which may be required for this Request to Deposit Account No. 19-0741.

Respectfully submitted,

Date: July 28, 2006

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MODIFIED PTO/SB/08 (08-00)
Approved for use through 10/31/2002. OMB 0651-0031

U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid OMB control

ADS Doo'd DOTO number. 28JUL 2006 Complete if Known Substitute for form 1449B/PTO **Application Number** Unassigned INFORMATION DISCLOSURE 01/28/2005 STATEMENT BY APPLICANT Filing Date Risho KOH First Named Inventor Date Submitted: July 28, 2006 Group Art Unit Unassigned **Examiner Name** Unassigned (use as many sheets as necessary) of 1 Attorney Docket Number 040373-0396 Sheet

				U.S. PATENT DOCUMENTS	5	
Examiner Initials*	Cite No.1	U.S. Patent Document			Date of Publication of	Pages, Columns, Lines, Where Relevant
		Number	Kind Code <sup>2</sup> (if known)	Name of Patentee or Applicant of Cited Document	Cited Document MM-DD-YYYY	Passages or Relevant Figures Appear
	A1	6,525,403	B2	INABA et al.	02-25-2003	

		UNPUBLISH	HED U.S. PATENT APPLICATION	DOCUMENTS	
Cite No. <sup>1</sup>	U.S. Patent Application Document		Name of Datastas or Applicant of	Filing Date of	Pages, Columns, Lines, Where Relevant
	Serial Number	Kind Code <sup>2</sup> (if known)	Cited Document	Cited Document MM-DD-YYYY	Passages or Relevant Figures Appear
		Cite Docume	Cite No. 1 Serial Number Code (if	Cite Document  No. Serial Number Code (if Code Code Code Code Code Code Code Code	Cite No. Serial Number Code (if Name of Patentee or Applicant of Cited Document MM-DD-YYYY

FOREIGN PATENT DOCUMENTS								
Examiner Initials*	Cite No.1	Office	Foreign Patent D e <sup>3</sup> Number <sup>4</sup>	ocument Kind Code <sup>5</sup> (if known)	Name of Patentee or Applicant of Cited Documents	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>6</sup>
	A2	JP	2003-298051	Α	LEE SOKO	10-17-2003		Α_
	A3	JP	2003-124463	Α	TOSHIBA CORP.	04-25-2003		Α_
	A4	JP	2002-110963		TOSHIBA CORP.	04-12-2002		Α
	A5	JP	2002-009289	A	NEC CORP.	01-11-2002		Α
	A6	JP	2001-298194		NEC CORP.	10-26-2001		Α_
	A7	JP	06-302817		KAWASAKI STEEL CORP.	10-28-1994		Α
	A8	JP	06-302816		KAWASAKI STEEL CORP.	10-28-1994		Α

Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s),	
publisher, city and/or country where published.	T°
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Examiner Signature		Date Considered	

Burden Hour Statement: This form is estimated to take 2.0 hours to complete. Time will vary depending upon the needs of the individual case. Any comments on the amount of time you are required to complete this form should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>&</sup>lt;sup>1</sup> Unique citation designation number. <sup>2</sup>See attached Kinds of U.S. Patent Documents. <sup>3</sup>Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup>For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup>Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>6</sup>Applicant is to place a check mark here if English language Translation is attached.